#### 2-OUTPUT VERY LOW POWER PCIE GEN 1-4 CLOCK GENERATOR

#### 9FGV0241

## **Description**

The 9FGV0241 is a 2-output very low power frequency generator for PCle Gen 1, 2, 3 and 4 applications with integrated output terminations providing Zo =  $100\Omega$ . The device has 2 output enables for clock management and supports 2 different spread spectrum levels in addition to spread off.

## **Recommended Application**

PCIe Gen1-4 clock generation for Riser Cards, Storage, Networking, JBOD, Communications, Access Points

## **Output Features**

- Two 0.7V low-power HCSL-compatible (LP-HCSL) DIF pairs with Zo =  $100\Omega$
- One 1.8V LVCMOS REF output w/Wake-On-LAN (WOL) support

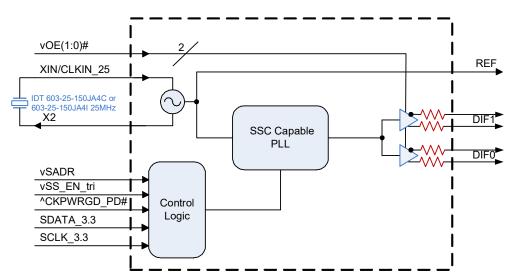
## **Key Specifications**

- DIF cycle-to-cycle jitter < 50ps
- DIF output-to-output skew < 50ps
- DIF phase jitter is PCle Gen1–4 compliant
- REF phase jitter is < 1.5ps RMS

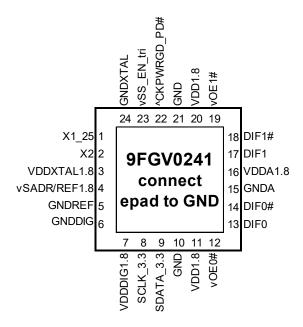
#### Features/Benefits

- Integrated terminations provide  $100\Omega$  differential Zo; reduced component count and board space
- 1.8V operation; reduced power consumption
- OE# pins; support DIF power management
- LP-HCSL differential clock outputs; reduced power and board space
- Programmable Slew rate for each output; allows tuning for various line lengths
- Programmable output amplitude; allows tuning for various application environments
- DIF outputs blocked until PLL is locked; clean system start-up
- Selectable 0%, -0.25% or -0.5% spread on DIF outputs; reduces EMI
- External 25MHz crystal; supports tight ppm with 0 ppm synthesis error
- Configuration can be accomplished with strapping pins;
   SMBus interface not required for device control
- 3.3V tolerant SMBus interface works with legacy controllers
- Space saving 4 x 4 mm 24-VFQFPN; minimal board space

## **Block Diagram**



## **Pin Configuration**



#### 24-pin VFQFPN, 4x4 mm, 0.5mm pitch

^ prefix indicates internal 120KOhm pull up resistor v prefix indicates internal 120KOhm pull down resistor

#### **SMBus Address Selection Table**

	SADR	Address	+ Read/Write Bit
State of SADR on first application	0	1101000	Х
of CKPWRGD PD#	1	1101010	х

#### **Power Management Table**

CKPWRGD PD#	SMBus	DI	REF	
CKFWKGD_FD#	OE bit	True O/P	Comp. O/P	NEF
0	Х	Low	Low	Hi-Z <sup>1</sup>
1	1	Running	Running	Running
1	0	Low	Low	Low

<sup>1.</sup> REF is Hi-Z until the 1st assertion of CKPWRGD\_PD# high. After this, when CKPWRG\_PD# is low, REF is Low.

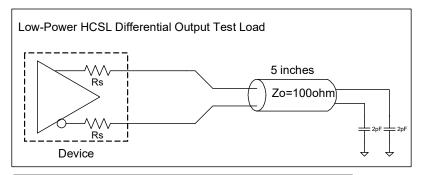
#### **Power Connections**

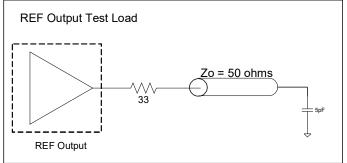
Pin Number		Deceriation		
VDD	GND	Description		
3	5,24	XTAL, REF		
7	6	Digital Power		
11,20	10,21	DIF outputs		
16	15	PLL Analog		

# **Pin Descriptions**

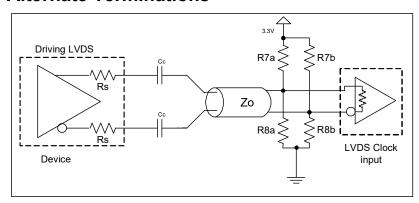
Pin#	Pin Name	Туре	Pin Description
1	X1_25	IN	Crystal input, Nominally 25.00MHz.
2	X2	OUT	Crystal output.
3	VDDXTAL1.8	PWR	Power supply for XTAL, nominal 1.8V
4	vSADR/REF1.8	LATCHED I/O	Latch to select SMBus Address/1.8V LVCMOS copy of X1 pin.
5	GNDREF	GND	Ground pin for the REF outputs.
6	GNDDIG	GND	Ground pin for digital circuitry
7	VDDDIG1.8	PWR	1.8V digital power (dirty power)
8	SCLK_3.3	IN	Clock pin of SMBus circuitry, 3.3V tolerant.
9	SDATA_3.3	I/O	Data pin for SMBus circuitry, 3.3V tolerant.
10	GND	GND	Ground pin.
11	VDD1.8	PWR	Power supply, nominal 1.8V
12	vOE0#	IN	Active low input for enabling DIF pair 0. This pin has an internal pull-down.
12			1 =disable outputs, 0 = enable outputs
13	DIF0	OUT	Differential true clock output
14	DIF0#	OUT	Differential Complementary clock output
15	GNDA	GND	Ground pin for the PLL core.
16	VDDA1.8	PWR	1.8V power for the PLL core.
17	DIF1	OUT	Differential true clock output
18	DIF1#	OUT	Differential Complementary clock output
19	vOE1#	IN	Active low input for enabling DIF pair 1. This pin has an internal pull-down.
19		IIN	1 =disable outputs, 0 = enable outputs
20	VDD1.8	PWR	Power supply, nominal 1.8V
21	GND	GND	Ground pin.
			Input notifies device to sample latched inputs and start up on first high assertion.
22	^CKPWRGD_PD#	IN	Low enters Power Down Mode, subsequent high assertions exit Power Down
			Mode. This pin has internal pull-up resistor.
23	VCC EN tri	LATCHED IN	Latched select input to select spread spectrum amount at initial power up :
23	vSS_EN_tri	LATCHED IN	1 = -0.5% spread, M = -0.25%, 0 = Spread Off
24	GNDXTAL	GND	GND for XTAL

## **Test Loads**





## **Alternate Terminations**



Driving LVDS inputs with the 9FGV0241

	,	√alue		
	Receiver has	Receiver has Receiver does not		
Component	termination	have termination	Note	
R7a, R7b	10K ohm	140 ohm		
R8a, R8b	5.6K ohm	75 ohm		
Сс	0.1 uF	0.1 uF		
Vcm	1.2 volts	1.2 volts		

## **Absolute Maximum Ratings**

Stresses above the ratings listed below can cause permanent damage to the 9FGV0241. These ratings, which are standard values for Renesas commercially rated parts, are stress ratings only. Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods can affect product reliability. Electrical parameters are guaranteed only over the recommended operating temperature range.

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
1.8V Supply Voltage	VDDxx	Applies to All VDD pins	-0.5		2.5	V	1,2
Input Voltage	$V_{IN}$		-0.5		$V_{DD}$ +0.3 $V$	V	1, 3
Input High Voltage, SMBus	V <sub>IHSMB</sub>	SMBus clock and data pins			3.6V	V	1
Storage Temperature	Ts		-65		150	°C	1
Junction Temperature	Tj				125	ç	1
Input ESD protection	ESD prot	Human Body Model	2000			V	1

<sup>&</sup>lt;sup>1</sup>Guaranteed by design and characterization, not 100% tested in production.

## **Electrical Characteristics–Current Consumption**

 $TA = T_{COM}$  or  $T_{IND}$ ; Supply Voltage per VDD of normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Operating Supply Current	I <sub>DDAOP</sub>	VDDA, PLL Mode, All outputs active @100MHz		7	8	mA	1
Operating Supply Current	I <sub>DDOP</sub>	VDD, All outputs active @100MHz		15	18	mA	1
Suspend Supply Current	I <sub>DDSUSP</sub>	VDDxxx, PD# = 0, Wake-On-LAN enabled		6	8	mA	1
Powerdown Current	I <sub>DDPD</sub>	PD#=0		0.6	1	mA	1, 2

<sup>&</sup>lt;sup>1</sup>Guaranteed by design and characterization, not 100% tested in production.

## Electrical Characteristics-Output Duty Cycle, Jitter, and Skew Characteristics

 $TA = T_{COM}$  or  $T_{IND}$ ; Supply Voltage per VDD of normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Duty Cycle	t <sub>DC</sub>	Measured differentially, PLL Mode	45	50	55	%	1
Skew, Output to Output	t <sub>sk3</sub>	V <sub>T</sub> = 50%		34	50	ps	1
Jitter, Cycle to cycle	t <sub>jcyc-cyc</sub>	PLL mode		14	50	ps	1,2

<sup>&</sup>lt;sup>1</sup>Guaranteed by design and characterization, not 100% tested in production.

<sup>&</sup>lt;sup>2</sup> Operation under these conditions is neither implied nor guaranteed.

<sup>&</sup>lt;sup>3</sup> Not to exceed 2.5V.

<sup>&</sup>lt;sup>2</sup>Assuming REF is not running in power down state

<sup>&</sup>lt;sup>2</sup> Measured from differential waveform

# **Electrical Characteristics-Input/Supply/Common Parameters-Normal Operating Conditions**

TA = T<sub>COM</sub> or T<sub>IND</sub>; Supply Voltage per VDD of normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
1.8V Supply Voltage	VDD	Supply voltage for core, analog and single-ended LVCMOS outputs	1.7	1.8	1.9	٧	1
Ambient Operating	T <sub>COM</sub>	Commmercial range	0	25	70	ŷ	1
Temperature	T <sub>IND</sub>	Industrial range	-40	25	85	°C	1
Input High Voltage	$V_{IH}$	Single-ended inputs, except SMBus	$0.75V_{DD}$		$V_{DD} + 0.3$	<b>V</b>	1
Input Mid Voltage	$V_{IM}$	Single-ended tri-level inputs ('_tri' suffix, if present)	$0.4~V_{DD}$		0.6 V <sub>DD</sub>	V	1
Input Low Voltage	$V_{IL}$	Single-ended inputs, except SMBus	-0.3		0.25 V <sub>DD</sub>	V	1
Schmitt Trigger Postive Going Threshold Voltage	V <sub>T+</sub>	Single-ended inputs, where indicated	0.4 V <sub>DD</sub>		0.7 V <sub>DD</sub>	<b>V</b>	1
Schmitt Trigger Negative Going Threshold Voltage	V <sub>T-</sub>	Single-ended inputs, where indicated	0.1 V <sub>DD</sub>		0.4 V <sub>DD</sub>	V	1
Hysteresis Voltage	$V_{H}$	$V_{T+}$ - $V_{T-}$	0.1 V <sub>DD</sub>		0.4 V <sub>DD</sub>	V	1
Output High Voltage	$V_{IH}$	Single-ended outputs, except SMBus. I <sub>OH</sub> = -2mA	V <sub>DD</sub> -0.45			V	1
Output Low Voltage	$V_{IL}$	Single-ended outputs, except SMBus. I <sub>OL</sub> = -2mA			0.45	V	1
	I <sub>IN</sub>	Single-ended inputs, $V_{IN}$ = GND, $V_{IN}$ = VDD	-5		5	uA	1
Input Current	I <sub>INP</sub>	Single-ended inputs $V_{IN}$ = 0 V; Inputs with internal pull-up resistors $V_{IN}$ = VDD; Inputs with internal pull-down resistors	-20		20	uA	1
Input Frequency	Fin	XTAL, or X1 input	23	25	27	MHz	1
Pin Inductance	$L_{pin}$	·			7	nΗ	1
Consoitance	C <sub>IN</sub>	Logic Inputs, except DIF_IN	1.5		5	pF	1
Capacitance	C <sub>OUT</sub>	Output pin capacitance			6	pF	1
Clk Stabilization	T <sub>STAB</sub>	From V <sub>DD</sub> Power-Up and after input clock stabilization or de-assertion of PD# to 1st clock		0.4	1.8	ms	1,2
SS Modulation Frequency	f <sub>MOD</sub>	Allowable Frequency (Triangular Modulation)	31	31.6	32	kHz	1
OE# Latency	t <sub>LATOE#</sub>	DIF start after OE# assertion DIF stop after OE# deassertion	2	3	4	clocks	1,3
Tdrive_PD#	t <sub>DRVPD</sub>	DIF output enable after PD# de-assertion		4	300	us	1,3
Tfall	t <sub>F</sub>	Fall time of single-ended control inputs			5	ns	1,2
Trise	t <sub>R</sub>	Rise time of single-ended control inputs			5	ns	1,2
SMBus Input Low Voltage	V <sub>ILSMB</sub>	$V_{DDSMB}$ = 3.3V, see note 4 for $V_{DDSMB}$ < 3.3V			0.8	V	1,4
SMBus Input High Voltage	V <sub>IHSMB</sub>	$V_{DDSMB}$ = 3.3V, see note 5 for $V_{DDSMB}$ < 3.3V	2.1		3.6	V	1,5
SMBus Output Low Voltage	V <sub>OLSMB</sub>	@ I <sub>PULLUP</sub>			0.4	V	1
SMBus Sink Current	I <sub>PULLUP</sub>	@ V <sub>OL</sub>	4			mA	1
Nominal Bus Voltage	$V_{DDSMB}$		1.7		3.6	V	1
SCLK/SDATA Rise Time	t <sub>RSMB</sub>	(Max VIL - 0.15) to (Min VIH + 0.15)			1000	ns	1
SCLK/SDATA Fall Time	t <sub>FSMB</sub>	(Min VIH + 0.15) to (Max VIL - 0.15)			300	ns	1
SMBus Operating Frequency	f <sub>MAXSMB</sub>	Maximum SMBus operating frequency			400	kHz	1

<sup>&</sup>lt;sup>1</sup> Guaranteed by design and characterization, not 100% tested in production.

 $<sup>^{2}\,\</sup>mbox{Control}$  input must be monotonic from 20% to 80% of input swing.

<sup>&</sup>lt;sup>3</sup> Time from deassertion until outputs are > 200mV.

 $<sup>^{4}</sup>$  For  $V_{DDSMB}$  < 3.3V,  $V_{ILSMB}$  < = 0.35 $V_{DDSMB}$ .

 $<sup>^{5}</sup>$  For  $V_{DDSMB}$  < 3.3V,  $V_{IHSMB}$  > = 0.65 $V_{DDSMB}$ .

## Electrical Characteristics-DIF 0.7V Low Power HCSL Outputs

TA = T<sub>COM</sub> or T<sub>IND</sub>. Supply Voltage per VDD of normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Slew rate	Trf	Scope averaging on 3.0V/ns setting	2	3.1	4.3	V/ns	1, 2, 3
Siew rate	111	Scope averaging on 2.0V/ns setting	1.5	2.3	3.5	V/ns	1, 2, 3
Slew rate matching	∆Trf	Slew rate matching, Scope averaging on		3	20	%	1,2,4
Voltage High	V <sub>HIGH</sub>	Statistical measurement on single-ended signal using oscilloscope math function. (Scope	660	794	850	mV	1,7
Voltage Low	$V_{LOW}$	averaging on)	-150	21	150	IIIV	1
Max Voltage	Vmax	Measurement on single ended signal using		816	1150	mV	1
Min Voltage	Vmin	absolute value. (Scope averaging off)	-300	-15		IIIV	1
Vswing	Vswing	Scope averaging off	300	1551		mV	1,2
Crossing Voltage (abs)	Vcross_abs	Scope averaging off	300	397	550	mV	1,5
Crossing Voltage (var)	Δ-Vcross	Scope averaging off		15	140	mV	1,6

<sup>&</sup>lt;sup>1</sup>Guaranteed by design and characterization, not 100% tested in production.

# Electrical Characteristics-Filtered Phase Jitter Parameters - PCle Common Clocked (CC) Architectures

T<sub>AMB</sub> = over the specified operating range. Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	Specification Limit	UNITS	NOTES
t <sub>jphPCleG1-CC</sub>		PCle Gen 1	21	25	35	86	ps (p-p)	1, 2, 3
		PCIe Gen 2 Low Band 10kHz < f < 1.5MHz (PLL BW of 5-16MHz, 8-16MHz, CDR = 5MHz)	0.9	0.9	1.1	3	ps (rms)	1, 2
ЧjphPCleG2-CC	t <sub>jphPCleG2-CC</sub> Phase Jitter, PLL Mode	PCle Gen 2 High Band 1.5MHz < f < Nyquist (50MHz) (PLL BW of 5-16MHz, 8-16MHz, CDR = 5MHz)	1.5	1.6	1.9	3.1	ps (ms)	1, 2
t <sub>jphPCleG3-CC</sub>		PCIe Gen 3 (PLL BW of 2-4MHz, 2-5MHz, CDR = 10MHz)	0.3	0.37	0.44	1	ps (ms)	1, 2
t <sub>jphPCleG4-CC</sub>		PCIe Gen 4 (PLL BW of 2-4MHz, 2-5MHz, CDR = 10MHz)	0.3	0.37	0.44	0.5	ps (ms)	1, 2

#### Notes on PCle Filtered Phase Jitter Tables

<sup>&</sup>lt;sup>2</sup> Measured from differential waveform

<sup>&</sup>lt;sup>3</sup> Slew rate is measured through the Vswing voltage range centered around differential 0V. This results in a +/-150mV window around differential 0V.

<sup>&</sup>lt;sup>4</sup> Matching applies to rising edge rate for Clock and falling edge rate for Clock#. It is measured using a +/-75mV window centered on the average cross point where Clock rising meets Clock# falling. The median cross point is used to calculate the voltage thresholds the oscilloscope is to use for the edge rate calculations.

<sup>&</sup>lt;sup>5</sup> Vcross is defined as voltage where Clock = Clock# measured on a component test board and only applies to the differential rising edge (i.e. Clock rising and Clock# falling).

<sup>&</sup>lt;sup>6</sup> The total variation of all Vcross measurements in any particular system. Note that this is a subset of Vcross\_min/max (Vcross absolute) allowed. The intent is to limit Vcross induced modulation by setting Δ-Vcross to be smaller than Vcross absolute.

<sup>&</sup>lt;sup>7</sup> At default SMBus settings.

<sup>&</sup>lt;sup>1</sup> Applies to all differential outputs, guaranteed by design and characterization.

<sup>&</sup>lt;sup>2</sup> Calculated from Intel-supplied Clock Jitter Tool, with spread on and off.

<sup>&</sup>lt;sup>3</sup> Sample size of at least 100K cycles. This figure extrapolates to 108ps pk-pk at 1M cycles for a BER of 1<sup>-12</sup>.

#### **Electrical Characteristics-REF**

TA = T<sub>COM</sub> or T<sub>IND</sub>; Supply Voltage per VDD of normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	Notes
Long Accuracy	ppm	see Tperiod min-max values		0		ppm	1,2
Clock period	$T_{period}$	25 MHz output nominal		40		ns	1,2
Rise/Fall Slew Rate	t <sub>rf1</sub>	Byte 3 = 1F, $V_{OH} = VDD-0.45V$ , $V_{OL} = 0.45V$	0.5	1	2.5	V/ns	1,3
Rise/Fall Slew Rate	t <sub>rf1</sub>	Byte 3 = 5F, $V_{OH}$ = VDD-0.45V, $V_{OL}$ = 0.45V	0.5	1.6	2.5	V/ns	1,3
Rise/Fall Slew Rate	t <sub>rf1</sub>	Byte 3 = 9F, $V_{OH}$ = VDD-0.45V, $V_{OL}$ = 0.45V	0.5	2	2.5	V/ns	1,3
Rise/Fall Slew Rate	t <sub>rf1</sub>	Byte 3 = DF, $V_{OH}$ = VDD-0.45V, $V_{OL}$ = 0.45V	0.5	2.1	2.5	V/ns	1,3
Duty Cycle	d <sub>t1</sub>	$V_T = VDD/2 V$	45	53.1	55	%	1,4
Duty Cycle Distortion	d <sub>tcd</sub>	$V_T = VDD/2 V$	0	2	4	%	1,5
Jitter, cycle to cycle	t <sub>jcyc-cyc</sub>	$V_T = VDD/2 V$		19	250	ps	1,4
Noise floor	t <sub>jdBc1k</sub>	1kHz offset		-130	-105	dBc	1,4
Noise floor	t <sub>jdBc10k</sub>	10kHz offset to Nyquist		-140	-120	dBc	1,4
Jitter, phase	t <sub>jphREF</sub>	12kHz to 5MHz		0.63	1.5	ps (rms)	1,4

<sup>&</sup>lt;sup>1</sup>Guaranteed by design and characterization, not 100% tested in production.

## Clock Periods-Differential Outputs with Spread Spectrum Disabled

		Measurement Window								
	Contor	1 Clock	1us	0.1s	0.1s	0.1s	1us	1 Clock		
SSC OFF	Center Freq. MHz	-c2c jitter AbsPer Min	-SSC Short-Term Average Min	- ppm Long-Term Average Min	0 ppm Period Nominal	+ ppm Long-Term Average Max	+SSC Short-Term Average Max	+c2c jitter AbsPer Max	Units	Notes
DIF	100.00	9.94900		9.99900	10.00000	10.00100		10.05100	ns	1,2

## Clock Periods-Differential Outputs with -0.5% Spread Spectrum Enabled

		Measurement Window								
	Center	1 Clock	1us	0.1s	0.1s	0.1s	1us	1 Clock		
SSC ON	Freq. MHz	-c2c jitter AbsPer Min	-SSC Short-Term Average Min	- ppm Long-Term Average Min	0 ppm Period Nominal	+ ppm Long-Term Average Max	+SSC Short-Term Average Max	+c2c jitter AbsPer Max	Units	Notes
DIF	99.75	9.94906	9.99906	10.02406	10.02506	10.02607	10.05107	10.10107	ns	1,2

<sup>&</sup>lt;sup>1</sup>Guaranteed by design and characterization, not 100% tested in production.

<sup>&</sup>lt;sup>2</sup> All Long Term Accuracy and Clock Period specifications are guaranteed assuming that REF is trimmed to 25.00 MHz

<sup>&</sup>lt;sup>3</sup> Typical value occurs when REF slew rate is set to default value

<sup>&</sup>lt;sup>4</sup> When driven by a crystal.

<sup>&</sup>lt;sup>5</sup> When driven by an external oscillator via the X1 pin. X2 should be floating in this case.

<sup>&</sup>lt;sup>2</sup> All Long Term Accuracy and Clock Period specifications are guaranteed assuming that REF is trimmed to 25.00 MHz

#### **General SMBus Serial Interface Information**

#### **How to Write**

- · Controller (host) sends a start bit
- · Controller (host) sends the write address
- Renesas clock will acknowledge
- Controller (host) sends the beginning byte location = N
- Renesas clock will acknowledge
- Controller (host) sends the byte count = X
- Renesas clock will acknowledge
- Controller (host) starts sending Byte N through Byte N+X-1
- Renesas clock will acknowledge each byte one at a time
- Controller (host) sends a Stop bit

	Index Block Write Operation							
Controll	er (Host)		Renesas (Slave/Receiver)					
Т	starT bit							
Slave A	Address							
WR	WRite							
			ACK					
Beginning	Byte = N							
			ACK					
Data Byte	Count = X							
			ACK					
Beginnin	g Byte N							
			ACK					
0		×						
0		X Byte	0					
0		e	0					
			0					
Byte N	+ X - 1							
			ACK					
Р	stoP bit							

Note: Read/Write address is determined by SADR latch.

#### How to Read

- · Controller (host) will send a start bit
- Controller (host) sends the write address
- Renesas clock will acknowledge
- Controller (host) sends the beginning byte location = N
- Renesas clock will acknowledge
- · Controller (host) will send a separate start bit
- · Controller (host) sends the read address
- Renesas clock will acknowledge
- Renesas clock will send the data byte count = X
- Renesas clock sends Byte N+X-1
- Renesas clock sends Byte 0 through Byte X (if X<sub>(H)</sub> was written to Byte 8)
- · Controller (host) will need to acknowledge each byte
- Controller (host) will send a not acknowledge bit
- · Controller (host) will send a stop bit

	Index Block F	Read O	peration
Cor	ntroller (Host)		Renesas
Т	starT bit		
SI	ave Address		
WR	WRite		
			ACK
Begi	nning Byte = N		
			ACK
RT	Repeat starT		
SI	ave Address		
RD	ReaD		
			ACK
			Data Byte Count=X
	ACK		
			Beginning Byte N
	ACK		
		ত্র	0
	0	X Byte	0
	0	×	0
	0		
			Byte N + X - 1
N	Not acknowledge		
Р	stoP bit		

#### SMBus Table: Output Enable Register

Byte 0	Name	Control Function	Type	0	1	Default
Bit 7		Reserved				1
Bit 6		Reserved				
Bit 5		Reserved				
Bit 4	Reserved					1
Bit 3		Reserved				1
Bit 2	DIF OE1	Output Enable	RW	Low/Low	Enabled	1
Bit 1	DIF OE0 Output Enable RW Low/Low Enabled					1
Bit 0		Reserved				1

#### SMBus Table: SS Readback and Vhigh Control Register

Byte 1	Name	Control Function	Type	0	1	Default
Bit 7	SSENRB1	SS Enable Readback Bit1	R	00' for SS_EN_tri = 0, '01' for SS_EN_tri		Latch
Bit 6	SSENRB1	SS Enable Readback Bit0	R	= 'M', '11 for S	S_EN_tri = '1'	Latch
Bit 5	SSEN_SWCNTRL	Enable SW control of SS	RW	SS control locked	Values in B1[4:3] control SS amount.	0
Bit 4	SSENSW1	SS Enable Software Ctl Bit1	RW <sup>1</sup>	00' = SS Off, '0	1' = -0.25% SS,	0
Bit 3	SSENSW0	SS Enable Software Ctl Bit0	RW <sup>1</sup>	'10' = Reserved	'11'= -0.5% SS	0
Bit 2		Reserved				1
Bit 1	AMPLITUDE 1	Controls Output Amplitude	RW	00 = 0.6V	01 = 0.7V	1
Bit 0	AMPLITUDE 0	- Controls Output Amplitude	RW	10= 0.8V	11 = 0.9V	0

<sup>1.</sup> B1[5] must be set to a 1 for these bits to have any effect on the part.

#### SMBus Table: DIF Slew Rate Control Register

Byte 2	Name	Control Function	Type	0	1	Default
Bit 7		Reserved				1
Bit 6	Reserved					
Bit 5	Reserved					
Bit 4	Reserved					1
Bit 3		Reserved				1
Bit 2	SLEWRATESEL DIF1	Adjust Slew Rate of DIF1	RW	2.0V/ns	3.0V/ns	1
Bit 1	SLEWRATESEL DIF0	Adjust Slew Rate of DIF0	RW	2.0V/ns	3.0V/ns	1
Bit 0		Reserved				1

#### SMBus Table: REF Control Register

Byte 3	Name	Control Function	Туре	0	1	Default
Bit 7	REF	Slew Rate Control	RW	00 = Slowest	01 = Slow	0
Bit 6	INLI	Siew Rate Contion	RW	10 = Fast	11 = Faster	1
Bit 5	REF Power Down Function	Wake-on-Lan Enable for REF	F RW RI	REF does not run in	REF runs in Power	0
DIT 3		Wake-on-Lan Enable for IVE		Power Down	Down	
Bit 4	REF OE	REF Output Enable	RW	Low	Enabled	1
Bit 3		Reserved				1
Bit 2	Reserved					1
Bit 1	Reserved					1
Bit 0		Reserved				1

Byte 4 is reserved and reads back 'hFF'.

#### SMBus Table: Revision and Vendor ID Register

Byte 5	Name	Control Function	Type	0	1	Default
Bit 7	RID3	Revision ID	R		0	
Bit 6	RID2		R	A rev = 0000		0
Bit 5	RID1		R			0
Bit 4	RID0		R		0	
Bit 3	VID3		R			0
Bit 2	VID2	VENDOR ID	R	0001	– IDT	0
Bit 1	VID1	VENDOR ID	R	0001	0001 = IDT	
Bit 0	VID0		R			1

#### SMBus Table: Device Type/Device ID

Byte 6	Name	Control Function	Type	0	1	Default
Bit 7	Device Type1	Device Type	R	00 = FGV,	01 = DBV,	0
Bit 6	Device Type0	Device Type	R	10 = DMV, 1	0	
Bit 5	Device ID5		R			0
Bit 4	Device ID4		R			0
Bit 3	Device ID3	Device ID	R	00010 binany or 02 boy	0	
Bit 2	Device ID2	Device ID	R	00010 biriai	00010 binary or 02 hex	
Bit 1	Device ID1		R			1
Bit 0	Device ID0		R			0

#### SMBus Table: Byte Count Register

Byte 7	Name	Control Function	Type	0	1	Default
Bit 7		Reserved				0
Bit 6	Reserved					0
Bit 5	Reserved					0
Bit 4	BC4		RW			0
Bit 3	BC3		RW	Writing to this regist	er will configure how	1
Bit 2	BC2	Byte Count Programming	RW	many bytes will be r	ead back, default is	0
Bit 1	BC1		RW	= 8 b	ytes.	0
Bit 0	BC0		RW			0

## Recommended Crystal Characteristics (3225 package)

PARAMETER	VALUE	UNITS	NOTES
Frequency	25	MHz	1
Resonance Mode	Fundamental	-	1
Frequency Tolerance @ 25°C	±20	PPM Max	1
Frequency Stability, ref @ 25°C Over Operating Temperature Range	±20	PPM Max	1
Temperature Range (commercial)	0~70	°C	1
Temperature Range (industrial)	-40~85	°C	2
Equivalent Series Resistance (ESR)	50	Ω Max	1
Shunt Capacitance (C <sub>O</sub> )	7	pF Max	1
Load Capacitance (C <sub>L</sub> )	8	pF Max	1
Drive Level	0.3	mW Max	1
Aging per year	±5	PPM Max	1

#### Notes:

- 1. FOX 603-25-150.
- 2. For I-temp, FOX 603-25-261.

#### **Thermal Characteristics**

PARAMETER	SYMBOL	CONDITIONS	PKG	TYP VALUE	UNITS	NOTES
Thermal Resistance	$\theta_{JC}$	Junction to Case	NLG20	62	°C/W	1
	$\theta_{Jb}$	Junction to Base		5.4	°C/W	1
	$\theta_{JA0}$	Junction to Air, still air		50	°C/W	1
	$\theta_{JA1}$	Junction to Air, 1 m/s air flow	NLG24	43	°C/W	1
	$\theta_{JA3}$	Junction to Air, 3 m/s air flow		39	°C/W	1
	$\theta_{JA5}$	Junction to Air, 5 m/s air flow		38	°C/W	1

<sup>&</sup>lt;sup>1</sup>ePad soldered to board

## **Package Outline Drawings**

The package outline drawings are located at the end of this document and are accessible from the Renesas website (see Ordering Information for POD links). The package information is the most current data available and is subject to change without revision of this document.

## **Marking Diagrams**





#### Notes:

- 1. "LOT" is the lot number.
- 2. "YYWW" is the last two digits of the year and week that the part was assembled.
- 3. "L" denotes RoHS compliant package.
- 4. "I" denotes industrial temperature grade.

## **Ordering Information**

Part Number	Carrier Type	Package	Temperature Range
9FGV0241AKLF	Tray	4 × 4 mm 24-VFQFPN	0 to +70°C
9FGV0241AKLFT	Tape and Reel	4 × 4 mm 24-VFQFPN	0 to +70°C
9FGV0241AKILF	Tray	4 × 4 mm 24-VFQFPN	-40°C to +85°C
9FGV0241AKILFT	Tape and Reel	4 × 4 mm 24-VFQFPN	-40°C to +85°C

<sup>&</sup>quot;LF" suffix to the part number are the Pb-Free configuration and are RoHS compliant.

<sup>&</sup>quot;A" is the device revision designator (will not correlate with the datasheet revision).

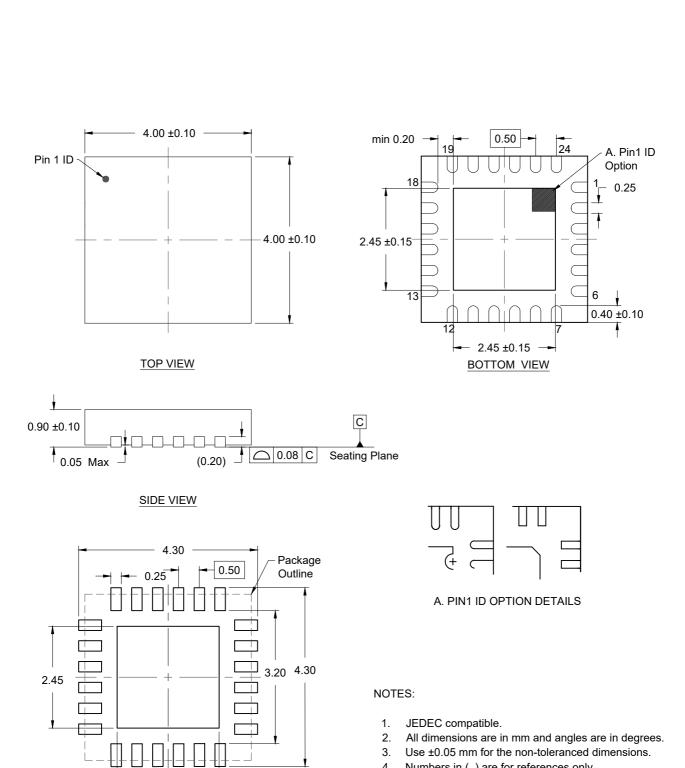
## **Revision History**

Date	Description
February 3, 2015	Updated IDDAOP and IDDOP typ and max specs per latest characterization review.
November 30, 2015	Updated block diagram.
January 4, 2016	Corrected typo in ordering information; changed rev "B" to rev "A".
October 18, 2016	Removed IDT crystal part number.
June 19, 2017	Updated front page Gendes to reflect the PCle Gen4 updates. Updated Electrical Characteristics - Filtered Phase Jitter Parameters - PCle Common Clocked (CC) Architectures and added PCle Gen4 Data.
June 6, 2019	Updated Input Current minimum and maximum values from -200/200uA to -20/20uA.
November 16, 2022	Changed Carrier Type in Ordering Information to Tray from Tubes.

### **Package Outline Drawing** PSC-4192-01



NLG24P1 24-VFQFPN 4.0 x 4.0 x 0.9 mm Body, 0.5mm Pitch Rev.06, May 6, 2025



RECOMMENDED LAND PATTERN (PCB Top View, NSMD Design)

2.45

- 4. Numbers in ( ) are for references only.
- Pin#1 ID is identified by either chamfer or notch.

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